

BFR 183 E6327 Information

Part Number BFR 183 E6327

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - RF

Description TRANSISTOR RF NPN 12V SOT-23

Package TO-236-3, SC-59, SOT-23-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BFR 183 E6327 Specifications

Manufacturer Part Number	BFR 183 E6327
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	12V
Frequency - Transition	8GHz
Noise Figure (dB Typ @ f)	0.9dB ~ 1.4dB @ 900MHz ~ 1.8GHz
Gain	17.5dB
Power - Max	450mW
DC Current Gain (hFE) (Min) @ Ic, Vce	70 @ 15mA, 8V
Current - Collector (Ic) (Max)	65mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	PG-SOT23-3
	Report errors?

BFR 183 E6327 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BFR 183 E6327 Payment Methods



















BFR 183 E6327 Shipping Methods













If you have any question about BFR 183 E6327, please do not hesitate to contact us!

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